

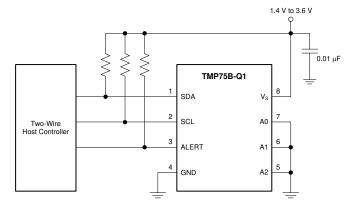
# TMP75B-Q1 1.8V Digital Temperature Sensor With Two-Wire Interface and Alert

### 1 Features

- Qualified for automotive applications
- AEC-Q100 qualified with the following results:
  - Temperature grade 1: –40°C to 125°C
  - HBM ESD classification 2
  - CDM ESD classification C4B
- Tri-Temp tested option: TMP75BTQDGKRQ1
- **Functional Safety-Capable** 
  - Documentation available to aid functional safety system design
- Digital output with two-wire serial interface
- Up to eight pin-programmable bus addresses
- Programmable overtemperature ALERT
- Shutdown mode for power saving
- One-shot conversion mode
- Operating temperature range: -40°C to 125°C
- Operating supply range: 1.4V to 3.6V
- Quiescent current:
  - 45µA Active (typical)
  - 0.3µA Shutdown (typical)
- Accuracy:
  - ±0.5°C (typical) from –20°C to 85°C
  - ±1°C (typical) from –40°C to 125°C
- Resolution: 12 bits (0.0625°C)
- Packages: SOIC-8 and VSSOP-8

### 2 Applications

- Autonomous driving module
- Media hub & display
- Head & digital cockpit unit
- Smart telematics & gateway
- ADAS domain controller & sensor fusion
- Body control module
- Onboard charger
- **Battery system**



**Simplified Schematic** 

## 3 Description

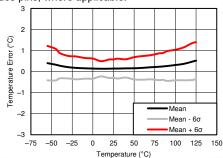
The TMP75B-Q1 is an integrated digital temperature sensor with a 12-bit analog-to-digital converter (ADC) that can operate at a 1.8V supply, and is pin and register compatible with the industry-standard LM75 and TMP75. This device is available in SOIC-8 and VSSOP-8 packages, and requires no external components to sense the temperature. The TMP75B-Q1 is capable of reading temperatures with a resolution of 0.0625°C with operating temperature range of -40°C to 125°C. The TMP75BTQDGKRQ1 is tri-temperature (-40°C, 25°C, and 125°C) tested in production for improved robustness.

The TMP75B-Q1 features SMBus and two-wire interface compatibility, and allows up to eight devices on the same bus with the SMBus overtemperature alert function. The programmable temperature limits and the ALERT pin allow the sensor to operate as a stand-alone thermostat, or an overtemperature alarm for power throttling or system shutdown. The factory-calibrated temperature accuracy and the noise-immune digital interface make the TMP75B-Q1 the preferred solution for temperature compensation of other sensors and electronic components. The TMP75B-Q1 is designed for thermal management and protection of a variety of automotive applications, and is a high-performance alternative to a PCB-mounted thermistor.

Package Information

r doktago imormation							
DEVICE NAME	PACKAGE (1)	PACKAGE SIZE <sup>(2)</sup>					
TMP75BQDRQ1	D (SOIC, 8)	4.9mm × 6mm					
TMP75BQDGKRQ1	DGK (VSSOP, 8)	3mm × 4.9mm					
TMP75BTQDGKRQ1							

- For all available packages, see Section 12. (1)
- The package size (length × width) is a nominal value and includes pins, where applicable.



**Temperature Accuracy (Error) vs Ambient Temperature** 



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# **4 Device Comparison**

## **Table 4-1. Device Comparison**

Device	Package	Production Test Condition
TMP75BQDRQ1	D (SOIC, 8 pin)	Room Temp (25°C)
TMP75BQDGKRQ1	DGK (VSSOP, 8 pin)	
TMP75BTQDGKRQ1	DGK (VSSOP, 8 pin)	Tri-temp (–40°C, 25°C, and 125°C)

# **5 Pin Configuration and Functions**

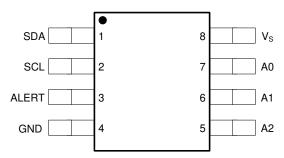


Figure 5-1. D and DGK Packages 8-Pin SOIC and 8-Pin VSSOP (Top View)

Table 5-1. Pin Functions

PI	PIN		DESCRIPTION
NAME	NO.	Type <sup>(1)</sup>	DESCRIPTION
A0	7	I	Address select. Connect to GND or V <sub>S</sub> .
A1	6	I	Address select. Connect to GND or V <sub>S</sub> .
A2	5	I	Address select. Connect to GND or V <sub>S</sub> .
ALERT	3	0	Overtemperature alert. Open-drain output; requires a pullup resistor.
GND	4	G	Ground
SCL	2	I	Serial clock
SDA	1	I/O	Serial data. Open-drain output; requires a pullup resistor.
Vs	8	I	Supply voltage, 1.4V to 3.6V

(1) I = input, O = output, I/O = input or output, and G = ground



## 6 Specifications

## **6.1 Absolute Maximum Ratings**

Over free-air temperature range (unless otherwise noted)(1)

				MIN	MAX	UNIT
Vs	Supply voltage	·			4	V
		SDA, SCL, ALERT, A2, A1		-0.3	4	V
V <sub>I/O</sub> I/O voltage	A0		-0.3	(V <sub>S</sub> ) + 0.3	V	
I <sub>SINK</sub>	Sink current	SDA, ALERT			10	mA
TJ	Operating junction tem	Operating junction temperature		<b>–</b> 55	150	°C
T <sub>stg</sub>	Storage temperature r	Storage temperature range		-60	150	°C

<sup>(1)</sup> Operation outside the Absolute Maximum Ratings may cause permanent device damage. Absolute Maximum Ratings do not imply functional operation of the device at these or any other conditions beyond those listed under Recommended Operating Conditions. If used outside the Recommended Operating Conditions but within the Absolute Maximum Ratings, the device may not be fully functional, and this may affect device reliability, functionality, performance, and shorten the device lifetime.

## 6.2 ESD Ratings

				MIN	MAX	UNIT
		Human body model (HBM), per AEC	Q100-002 <sup>(1)</sup>	-2000	2000	V
V <sub>(ESD)</sub>	V <sub>(ESD)</sub> Electrostatic discharge Charged device model (CDM), per AEC Q100-011	Charged device model (CDM), per	Corner pins (1, 4, 5, and 8)	-1000	1000	V
		Other pins	-1000	1000	V	

<sup>(1)</sup> AEC Q100-002 indicates HBM stressing is done in accordance with the ANSI/ESDA/JEDEC JS-001 specification.

## **6.3 Recommended Operating Conditions**

over operating free-air temperature range (unless otherwise noted)

	MIN	NOM	MAX	UNIT
Supply voltage	1.4	1.8	3.6	V
Operating free-air temperature, T <sub>A</sub>	-40		125	°C

#### 6.4 Thermal Information

THERMAL METRIC <sup>(1)</sup>		TMP75BQDRQ1	TMP75BQDGK RQ1	TMP75BTQDG KRQ1	
		D (SOIC)	DGK (VSSOP)	DGK (VSSOP)	UNIT
		8 PINS	8 PINS	8 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance	125.4	188.1	188.1	
R <sub>0JC(top)</sub>	Junction-to-case (top) thermal resistance	71.5	79.1	79.1	
$R_{\theta JB}$	Junction-to-board thermal resistance	65.8	109.6	109.6	°C/W
ΨЈТ	Junction-to-top characterization parameter	21.1	15.3	15.3	C/VV
ΨЈВ	Junction-to-board characterization parameter	65.3	108	108	
R <sub>0JC(bot)</sub>	Junction-to-case (bottom) thermal resistance	N/A	N/A	N/A	

<sup>(1)</sup> For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application note.

Product Folder Links: TMP75B-Q1



## **6.5 Electrical Characteristics**

At  $T_A = -40$ °C to 125°C and  $V_S = 1.4$  V to 3.6 V, unless otherwise noted. Typical values at  $T_A = 25$ °C and  $V_S = 1.8$  V

	PARAMETER	TES	TEST CONDITIONS			MAX	UNIT
TEMP	ERATURE SENSOR						
	Temperature Range			-40		125	°C
	Temperature resolution				0.0625		°C
		TMP75BQDGKRQ1	-20°C to 85°C		±0.5	±2	°C
	Temperature accuracy (error)	TMP75BQDRQ1	-40°C to 125°C		±1	±3	°C
	(GITOT)	TMP75BTQDGKRQ1	-40°C to 125°C		±0.5	±2	°C
DIGITA	AL INPUT/OUTPUT		1				
V <sub>IH</sub>	High-level input voltage			0.7(V <sub>S</sub> )		Vs	V
V <sub>IL</sub>	Low-level input voltage			-0.3		0.3(V <sub>S</sub> )	V
I <sub>IN</sub>	Input current	0 V< V <sub>IN</sub> < (V <sub>S</sub> ) + 0.3 V	V			1	μA
V <sub>OL</sub>	Laurianal antonit valta aa	V <sub>S</sub> ≥ 2 V, I <sub>OUT</sub> = 3 mA	V <sub>S</sub> ≥ 2 V, I <sub>OUT</sub> = 3 mA			0.4	V
$V_{OL}$	Low-level output voltage	V <sub>S</sub> < 2 V, I <sub>OUT</sub> = 3 mA		0		0.2(V <sub>S</sub> )	V
	ADC resolution				12		Bits
	Conversion time	One-shot mode	One-shot mode		27	35	ms
	Conversion modes	CR1 = 0, CR0 = 0 (def	ault)		37		Conv/s
		CR1 = 0, CR0 = 1			18		Conv/s
		CR1 = 1, CR0 = 0			9		Conv/s
		CR1 = 1, CR0 = 1			4		Conv/s
	Timeout time			38	54	70	ms
POWE	R SUPPLY						
	Operating supply range			1.4		3.6	V
		Serial bus inactive, CR	1 = 0, CR0 = 0 (default)		45	89	μA
	Quiescent current	Serial bus inactive, CR	1 = 0, CR0 = 1		22	48	μA
I <sub>Q</sub> Quiescent	Quiescent current	Serial bus inactive, CR1 = 1, CR0 = 0			12	30	μΑ
		Serial bus inactive, CR	1 = 1, CR0 = 1		6.5	21	μΑ
		Serial bus inactive			0.3	8	μΑ
$I_{SD}$	Shutdown current	Serial bus active, SCL	frequency = 400 kHz		10		μA
		Serial bus active, SCL frequency = 3.4 MHz			80		μA

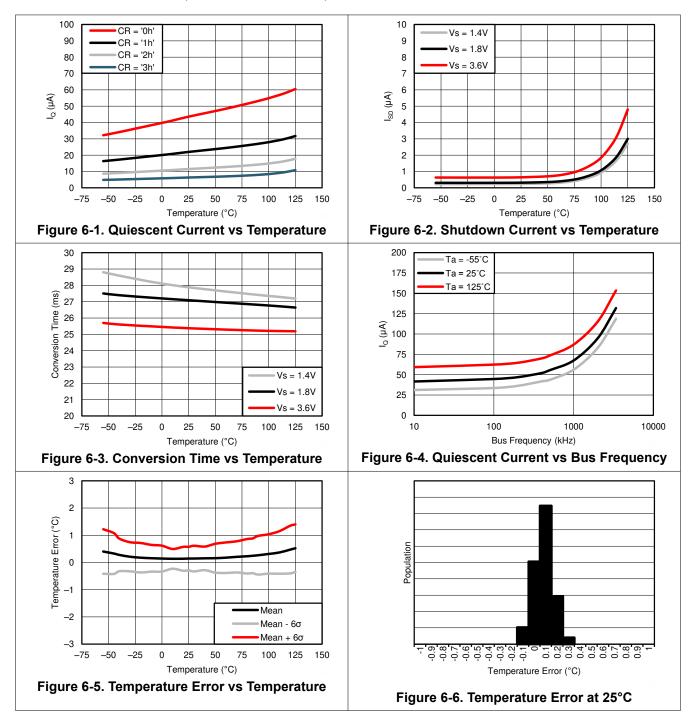


# **6.6 Timing Requirements**

			STA	NDARD	FAS	T-MODE		
			Min	Max	Min	Max	UNIT	
_	COL an aretime for average	V <sub>S</sub> ≥ 1.8 V	0.001	0.4	0.001	3	MHz	
f <sub>SCL</sub>	SCL operating frequency	V <sub>S</sub> < 1.8 V	0.001	0.4	0.001	2.5	MHz	
4	Bus-free time between STOP and	V <sub>S</sub> ≥ 1.8 V	1300		160		ns	
t <sub>(BUF)</sub>	START conditions	V <sub>S</sub> < 1.8 V	1300		260		ns	
t <sub>(HDSTA)</sub>	Hold time after repeated START condition.  After this period, the first clock is generated.		600		160		ns	
t <sub>(SUSTA)</sub>	Repeated START condition setup time		600		160		ns	
t <sub>(SUSTO)</sub>	STOP condition setup time		600		160		ns	
	Data hold time	V <sub>S</sub> ≥ 1.8 V	0	900	0	100	ns	
t <sub>(HDDAT)</sub>		V <sub>S</sub> < 1.8 V	0	900	0	140	ns	
+	Data setup time	V <sub>S</sub> ≥ 1.8 V	100		10		ns	
t <sub>(SUDAT)</sub>	Data setup time	V <sub>S</sub> < 1.8 V	100		20		ns	
4	SCI plant law period	V <sub>S</sub> ≥ 1.8 V	1300		190		ns	
$t_{(LOW)}$	SCL clock low period	V <sub>S</sub> < 1.8 V	1300		240		ns	
t <sub>(HIGH)</sub>	SCL clock high period		600		60		ns	
t <sub>R(SDA)</sub> , t <sub>F(SDA)</sub>	Data rise and fall time			300		80	ns	
t <sub>R(SCL)</sub> , t <sub>F(SCL)</sub>	Clock rise and fall time			300		40	ns	
t <sub>R</sub>	Clock and data rise time for SCLK ≤ 1	00 kHz		1000			ns	

## **6.7 Typical Characteristics**

At  $T_A = 25$ °C and  $V_S = 1.8V$  (unless otherwise noted).





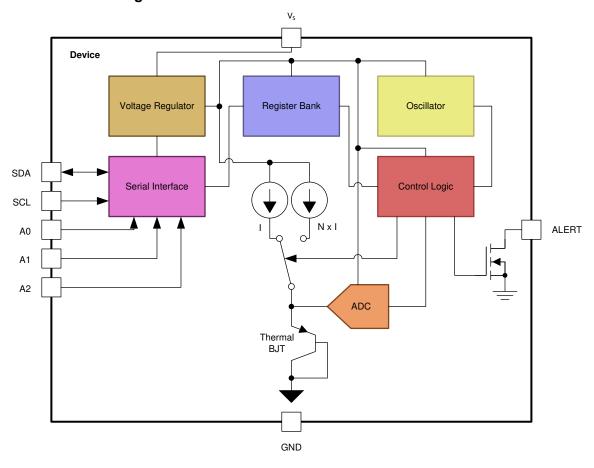
# 7 Detailed Description

### 7.1 Overview

The TMP75B-Q1 is a digital temperature sensor optimal for thermal management and thermal protection applications. The TMP75B-Q1 is two-wire and SMBus interface compatible, and is specified over a temperature range of -40°C to 125°C. The TMP75BTQDGKRQ1 is tri-temperature (-40°C, 25°C, and 125°C) tested in production for improved robustness.

The temperature sensing device for the TMP75B-Q1 is the chip. A bipolar junction transistor (BJT) inside the chip is used in a band-gap configuration to produce a voltage proportional to the chip temperature. The voltage is digitized and converted to a 12-bit temperature result in degrees Celsius, with a resolution of 0.0625°C. The package leads provide the primary thermal path because of the lower thermal resistance of the metal. Thus, the temperature result is equivalent to the local temperature of the printed circuit board (PCB) where the sensor is mounted.

## 7.2 Functional Block Diagram



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## 7.3 Feature Description

### 7.3.1 Digital Temperature Output

The 12-bit digital output from each temperature measurement conversion is stored in the read-only temperature register. Two bytes must be read to obtain the data; see Figure 8-2. Note that byte 1 is the most significant byte, followed by byte 2, the least significant byte. The temperature result is left-justified with the 12 most significant bits used to indicate the temperature. There is no need to read the second byte if resolution below 1°C is not required. Table 7-1 summarizes the temperature data format. One LSB equals 0.0625°C. Negative numbers are represented in binary 2's complement format.

Table 7-1. Temperature Data Format

	DIGITAL OL	JTPUT
TEMPERATURE (°C) (1)	BINARY	HEX
128	0111 1111 1111	7FF
127.9375	0111 1111 1111	7FF
100	0110 0100 0000	640
80	0101 0000 0000	500
75	0100 1011 0000	4B0
50	0011 0010 0000	320
25	0001 1001 0000	190
0.25	0000 0000 0100	004
0	0000 0000 0000	000
-0.25	1111 1111 1100	FFC
-25	1110 0111 0000	E70
<b>–</b> 55	1100 1001 0000	C90

<sup>(1)</sup> The temperature sensor resolution is 0.0625°C/LSB.

Table 7-1 does not supply a full list of all temperatures. Use the following rules to obtain the digital data format for a given temperature, and so forth.

To convert positive temperatures to a digital data format:

Divide the temperature by the resolution. Then, convert the result to binary code with a 12-bit, left-justified format, and MSB = 0 to denote a positive sign.

Example:  $(50^{\circ}C) / (0.0625^{\circ}C / LSB) = 800 = 320h = 0011 0010 0000$ 

To convert a positive digital data format to temperature:

Convert the 12-bit, left-justified binary temperature result, with the MSB = 0 to denote a positive sign, to a decimal number. Then, multiply the decimal number by the resolution to obtain the positive temperature.

Example:  $0011\ 0010\ 0000 = 320h = 800 \times (0.0625^{\circ}C / LSB) = 50^{\circ}C$ 

To convert negative temperatures to a digital data format:

Divide the absolute value of the temperature by the resolution, and convert the result to binary code with a 12-bit, left-justified format. Then, generate the 2's complement of the result by complementing the binary number and adding one. Denote a negative number with MSB = 1.

Example:  $(|-25^{\circ}C|) / (0.0625^{\circ}C / LSB) = 400 = 190h = 0001 1001 0000$ 

Two's complement format: 1110 0110 1111 + 1 = 1110 0111 0000

To convert a negative digital data format to temperature:

Generate the 2's compliment of the 12-bit, left-justified binary number of the temperature result (with MSB = 1, denoting negative temperature result) by complementing the binary number and adding one. This represents

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the binary number of the absolute value of the temperature. Convert to decimal number and multiply by the resolution to get the absolute temperature, then multiply by -1 for the negative sign.

Example: 1110 0111 0000 has twos compliment of 0001 1001 0000 = 0001 1000 1111 + 1

Convert to temperature: 0001 1001 0000 = 190h = 400;  $400 \times (0.0625^{\circ}\text{C} / \text{LSB}) = 25^{\circ}\text{C} = (|-25^{\circ}\text{C}|); (|-25^{\circ}\text{C}|) \times (-1) = -25^{\circ}\text{C}$ 

#### 7.3.2 Temperature Limits and Alert

The temperature limits are stored in the  $T_{LOW}$  and  $T_{HIGH}$  registers (Table 8-4 and Table 8-5) in the same format as the temperature result, and the values are compared to the temperature result on every conversion. The outcome of the comparison drives the behavior of the ALERT pin, which can operate as a comparator output or an interrupt, and is set by the TM bit in the configuration register (Table 8-3).

In comparator mode (TM = 0, default), the ALERT pin becomes active when the temperature is equal to or exceeds the value in  $T_{HIGH}$  (fault conditions) for a consecutive number of conversions as set by the FQ bits of the configuration register. ALERT clears when the temperature falls below  $T_{LOW}$  for the same consecutive number of conversions. The difference between the two limits acts as a hysteresis on the comparator output, and a fault counter prevents false alerts as a result of environmental noise.

In interrupt mode (TM = 1), the ALERT pin becomes active when the temperature equals or exceeds the value in  $T_{HIGH}$  for a consecutive number of fault conditions. The ALERT pin remains active until a read operation of any register occurs, or the device successfully responds to the SMBus alert response address. The ALERT pin is also cleared if the device is placed in shutdown mode (see the *Shutdown Mode* section for shutdown mode description). After the ALERT pin is cleared, this pin becomes active again only when the temperature falls below  $T_{LOW}$  for a consecutive number of fault conditions, and remains active until cleared by a read operation of any register, or a successful response to the SMBus alert response address. After the ALERT pin is cleared, the cycle repeats with the ALERT pin becoming active when the temperature equals or exceeds  $T_{HIGH}$ , and so on. The ALERT pin can also be cleared by resetting the device with the general-call reset command. This action also clears the state of the internal registers in the device and the fault counter memory, returning the device to comparator mode (TM = 0).

The active state of the ALERT pin is set by the POL bit in the configuration register. When POL = 0 (default), the ALERT pin is active low. When POL = 1, the ALERT pin is active high. The operation of the ALERT pin in various modes is shown in Figure 7-1.

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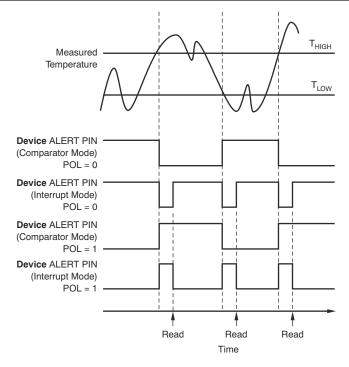


Figure 7-1. ALERT Pin Modes of Operation

#### 7.3.3 Serial Interface

The TMP75B-Q1 operates as a target device only on the two-wire bus and SMBus. Connections to the bus are made using the open-drain I/O lines, SDA and SCL. The SDA and SCL pins feature integrated spike-suppression filters and Schmitt triggers to minimize the effects of input spikes and bus noise. The TMP75B-Q1 supports the transmission protocol for both fast (1kHz to 400kHz) and high-speed (1kHz to 3MHz) modes. All data bytes are transmitted MSB first.

#### 7.3.3.1 Bus Overview

The device that initiates the transfer is called a *controller*, and the devices controlled by the controller are *targets*. The bus must be controlled by a controller device that generates the serial clock (SCL), controls the bus access, and generates the start and stop conditions.

To address a specific device, initiate a start condition by pulling the data line (SDA) from a high to a low logic level while SCL is high. All targets on the bus shift in the target address byte; the last bit indicates whether a read or write operation follows. During the ninth clock pulse, the target being addressed responds to the controller by generating an acknowledge bit and pulling SDA low.

Data transfer is then initiated and sent over eight clock pulses followed by an acknowledge bit. During data transfer, SDA must remain stable while SCL is high because any change in SDA while SCL is high is interpreted as a start or stop signal.

After all data have been transferred, the controller generates a stop condition indicated by pulling SDA from low to high, while SCL is high.

#### 7.3.3.2 Serial Bus Address

To communicate with the TMP75B-Q1, the controller must first communicate with target devices using a target address byte. The target address byte consists of seven address bits, and a direction bit indicating the intent of executing either a read or write operation. The TMP75B-Q1 features three address pins that allow up to eight devices to be addressed on a single bus. The TMP75B-Q1 latches the status of the address pins at the start of a communication. Table 7-2 describes the pin logic levels and the corresponding address values.



Table 7-2. Address Pin Connections and 1	Target Addresses
--	------------------

DEVICE TWO-WIRE ADDRESS	A2	A1	Α0
1001000	GND	GND	GND
1001001	GND	GND	Vs
1001010	GND	V <sub>S</sub>	GND
1001011	GND	Vs	Vs
1001100	Vs	GND	GND
1001101	V <sub>S</sub>	GND	V <sub>S</sub>
1001110	Vs	Vs	GND
1001111	Vs	Vs	Vs

#### 7.3.3.3 Writing and Reading Operation

Accessing a particular register on the TMP75B-Q1 is accomplished by writing the appropriate value to the pointer register. The value for the pointer register is the first byte transferred after the target address byte with the R/W bit low. Every write operation to the TMP75B-Q1 requires a value for the pointer register (see Figure 7-3).

When reading from the TMP75B-Q1, the last value stored in the pointer register by a write operation is used to determine which register is read by a read operation. To change the register pointer for a read operation, a new value must be written to the pointer register. This action is accomplished by issuing a target address byte with the R/W bit low, followed by the pointer register byte. No additional data are required. The controller can then generate a start condition and send the target address byte with the R/W bit high to initiate the read command. See Figure 7-4 for details of this sequence. If repeated reads from the same register are desired, there is no need to continually send the pointer register bytes because the TMP75B-Q1 stores the pointer register value until the value is changed by the next write operation.

Note that register bytes are sent with the most significant byte first, followed by the least significant byte.

#### 7.3.3.4 Target-Mode Operations

The TMP75B-Q1 can operate as a target receiver or target transmitter.

#### 7.3.3.4.1 Target Receiver Mode:

The first byte transmitted by the controller is the target address, with the R/W bit low. The TMP75B-Q1 then acknowledges reception of a valid address. The next byte transmitted by the controller is the pointer register. The TMP75B-Q1 then acknowledges reception of the pointer register byte. The next byte or bytes are written to the register addressed by the pointer register. The TMP75B-Q1 acknowledges reception of each data byte. The controller can terminate data transfer by generating a start or stop condition.

#### 7.3.3.4.2 Target Transmitter Mode:

The first byte transmitted by the controller is the target address, with the R/W bit high. The target acknowledges reception of a valid target address. The next byte is transmitted by the target and is the most significant byte of the register indicated by the pointer register. The controller acknowledges reception of the data byte. The next byte transmitted by the target is the least significant byte. The controller acknowledges reception of the data byte. The controller can terminate data transfer by generating a not-acknowledge bit on reception of any data byte, or by generating a start or stop condition.

#### 7.3.3.5 SMBus Alert Function

The TMP75B-Q1 supports the SMBus alert function. When the TMP75B-Q1 operates in interrupt mode (TM = 1), the ALERT pin can be connected as an SMBus alert signal. When a controller senses that an alert condition is present on the ALERT line, the controller sends an SMBus alert command (00011001) to the bus. If the ALERT pin is active, the device acknowledges the SMBus alert command and responds by returning the target address on the SDA line. The eighth bit (LSB) of the target address byte indicates whether the alert condition is caused by the temperature exceeding  $T_{HIGH}$  or falling below  $T_{LOW}$ . The LSB is high if the temperature is greater than  $T_{HIGH}$ , or low if the temperature is less than  $T_{LOW}$ . See Figure 7-5 for details of this sequence.

If multiple devices on the bus respond to the SMBus alert command, arbitration during the target address portion of the SMBus alert command determines which device clears the alert status first. If the TMP75B-Q1 wins the arbitration, the ALERT pin becomes inactive at the completion of the SMBus alert command. If the TMP75B-Q1 loses the arbitration, the ALERT pin remains active.

#### 7.3.3.6 General Call

The TMP75B-Q1 responds to a two-wire general call address (0000000) if the eighth bit is 0. The device acknowledges the general call address and responds to commands in the second byte. If the second byte is 00000100, the TMP75B-Q1 latches the status of the address pin, but does not reset. If the second byte is 00000110, the TMP75B-Q1 internal registers are reset to power-up values.

### 7.3.3.7 High-Speed (Hs) Mode

For the two-wire bus to operate at frequencies above 400kHz, the controller device must issue an SMBus Hs-mode controller code (00001xxx) as the first byte after a start condition to switch the bus to high-speed operation. The TMP75B-Q1 does not acknowledge this byte, but does switch the input filters on SDA and SCL and the output filters on SDA to operate in Hs-mode, allowing transfers at up to 3MHz. After the Hs-mode controller code has been issued, the controller transmits a two-wire target address to initiate a data-transfer operation. The bus continues to operate in Hs-mode until a stop condition occurs on the bus. Upon receiving the stop condition, the TMP75B-Q1 switches the input and output filters back to fast-mode operation.

#### 7.3.3.8 Timeout Function

The TMP75B-Q1 resets the serial interface if SCL or SDA are held low for 54ms (typical) between a start and stop condition. If the TMP75B-Q1 is pulled low, the device releases the bus and then waits for a start condition. To avoid activating the timeout function, maintaining a communication speed of at least 1kHz is necessary for the SCL operating frequency.

#### 7.3.3.9 Two-Wire Timing

Acknowledge

The TMP75B-Q1 is two-wire and SMBus compatible. Figure 7-2 to Figure 7-5 describe the various operations on the TMP75B-Q1. Parameters for Figure 7-2 are defined in Section 6.6. Bus definitions are:

Bus Idle	Both SDA and SCL lines remain high.
Start Data Transfer	A change in the state of the SDA line, from high to low, while the SCL line is high defines a start condition. Each data transfer is initiated with a start condition.
Stop Data Transfer	A change in the state of the SDA line from low to high while the SCL line is high defines a stop condition. Each data transfer is terminated with a repeated start or stop condition.

**Data Transfer** The number of data bytes transferred between a start and a stop condition is not limited, and is determined by the controller device.

> The receiver acknowledges the transfer of data. Using the TMP75B-Q1 for single-byte updates is also possible. To update only the MS byte, terminate communication by issuing a

start or stop condition on the bus.

Each receiving device, when addressed, must generate an acknowledge bit.

A device that acknowledges must pull down the SDA line during the acknowledge clock pulse so that the SDA line is stable low during the high period of the acknowledge clock pulse. Setup and hold times must be taken into account. When a controller receives data, the termination of the data transfer can be signaled by the controller generating a

not-acknowledge (1) on the last byte transmitted by the target.



### 7.3.3.10 Two-Wire Timing Diagrams

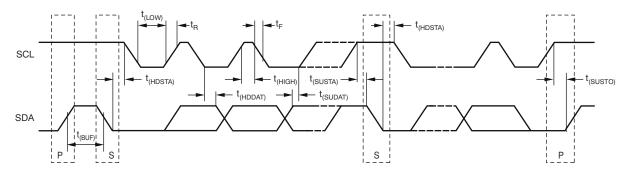
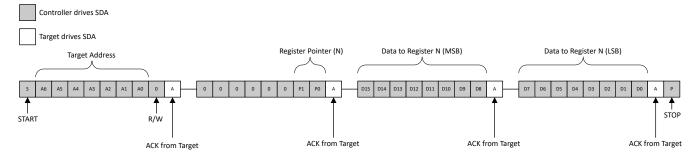


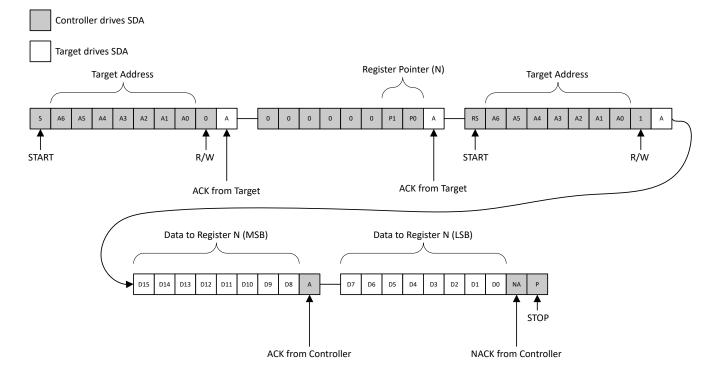
Figure 7-2. Two-Wire Timing Diagram



### Note

The value of A7 through A0 are determined by the connections of the corresponding pins. See also Table 7-2.

Figure 7-3. Two-Wire Timing Diagram for Write Word Format



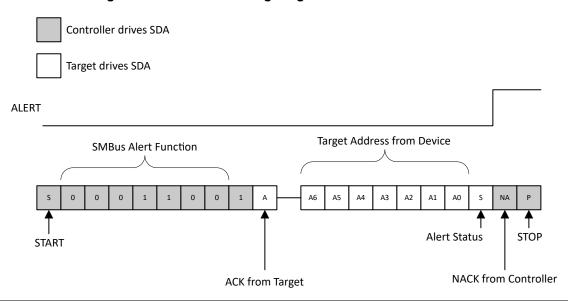
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#### **Note**

The value of A7 through A0 are determined by the connections of the corresponding pins. See also Table 7-2.

Figure 7-4. Two-Wire Timing Diagram for Read Word Format



#### Note

The value of A7 through A0 are determined by the connections of the corresponding pins. See also Table 7-2.

Figure 7-5. Timing Diagram for SMBus Alert

#### 7.4 Device Functional Modes

#### 7.4.1 Continuous-Conversion Mode

The default mode of the TMP75B-Q1 is continuous conversion, where the ADC performs continuous temperature conversions and stores each result to the temperature register, overwriting the result from the previous conversion. Conversion rate bits CR1 and CR0 in the configuration register configure the TMP75B-Q1 for typical conversion rates of 37Hz, 18Hz, 9Hz, or 4Hz. The TMP75B-Q1 has a typical conversion time of 27ms. To achieve different conversion rates, the TMP75B-Q1 makes a conversion, and then powers down and waits for the appropriate delay set by CR1 and CR0. The default rate is 37Hz (no delay between conversions). Table 7-3 shows the settings for CR1 and CR0.

**Table 7-3. Conversion Rate Settings** 

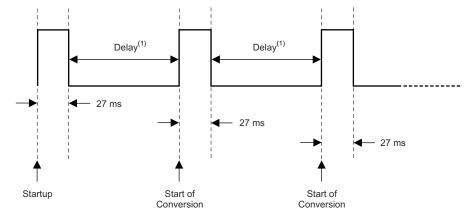
CR1	CR0	CONVERSION RATE (TYP)	I <sub>Q</sub> (TYP)
0	0	37Hz (continuous conversion, default)	45µA
0	1	18Hz	22μΑ
1	0	9Hz	12µA
1	1	4Hz	6.5µA

After power-up or a general-call reset, the TMP75B-Q1 immediately starts a conversion, as shown in Figure 7-6. The first result is available after 27ms (typical). The active quiescent current during conversion is 45µA (typical at 25°C). The quiescent current during delay is 1µA (typical at 25°C).

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A. Delay is set by the CR bits in the configuration register.

Figure 7-6. Conversion Start

#### 7.4.2 Shutdown Mode

Shutdown mode saves maximum power by shutting down all device circuitry other than the serial interface, and reduces current consumption to typically less than  $0.3\mu A$ . Shutdown mode is enabled when the SD bit in the configuration register is set to 1; the device shuts down after the current conversion is completed. When SD is equal to 0, the device operates in continuous-conversion mode. When shutdown mode is enabled, the ALERT pin and fault counter clear in both comparator and interrupt modes; however, this clearing occurs with the rising edge of the shutdown signal. After shutdown is enabled, reprogramming shutdown does not clear the ALERT pin and the fault counter until a rising edge is generated on the shutdown signal.

#### 7.4.3 One-Shot Mode

The TMP75B-Q1 features a *one-shot* temperature measurement mode. When the device is in shutdown mode, writing a 1 to the OS bit starts a single temperature conversion. The device returns to the shutdown state at the completion of the single conversion. This mode reduces power consumption in the TMP75B-Q1 when continuous temperature monitoring is not required. When the configuration register is read, the OS bit always reads zero.

## 7.5 Programming

Figure 7-7 shows the internal register structure of the TMP75B-Q1. Use the 8-bit pointer register to address a given data register. The pointer register uses the two LSBs to identify which of the data registers respond to a read or write command. Figure 8-1 identifies the bits of the pointer register byte.

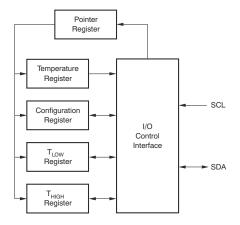


Figure 7-7. Internal Register Structure

## 8 Register Map

Table 8-1 describes the registers available in the TMP75B-Q1 with the corresponding pointer addresses, followed by the description of the bits in each register.

Table 8-1. Register Map and Pointer Addresses

		9
P1	P0	REGISTER
0	0	Temperature register (read only, default)
0	1	Configuration register (read/write)
1	0	T <sub>LOW</sub> register (read/write)
1	1	T <sub>HIGH</sub> register (read/write)

Figure 8-1. Pointer Register (pointer = N/A) [reset = 00h]

7	6	5	4	3	2	1	0
	Reserved					P1	P0
	W-0h					W-0h	W-0h

LEGEND: R/W = Read/Write; R = Read only; W = Write only; -n = value after reset

Figure 8-2. Temperature Register (pointer = 0h) [reset = 0000h]

		· · · · · · · · · · · · · · · · · · ·	o. (po			9	
8	9	10	11	12	13	14	15
T4	T5	T6	T7	Т8	Т9	T10	T11
		·	0h	R-			
0	1	2	3	4	5	6	7
	erved	Res		T0	T1	T2	T3
	-0h	R		R-0h			

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

### **Table 8-2. Temperature Register Description**

Name	Description			
T11 to T4	The 8 MSBs of the temperature result (resolution of 1°C)			
T3 to T0	The 4 LSBs of the temperature result (resolution of 0.0625°C)			

Figure 8-3. Configuration Register (pointer = 1h) [reset = 00FFh]

					,		
15	14	13	12	11	10	9	8
os	CI	R	FQ		POL	TM	SD
R/W-0h	R/W	R/W-0h		R/W-0h		R/W-0h	R/W-0h
7	6	5	4	3	2	1	0
Reserved							
R-FFh							

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

## **Table 8-3. Configuration Register Description**

Name	Description			
os	One-shot mode			
	In shutdown (SD = 1), write 1 to start a conversion. OS always reads back 0.			

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**Table 8-3. Configuration Register Description (continued)** 

Name	Description
CR	Conversion rate control  CR = 0h: 37Hz conversion rate (typ) (default)  CR = 1h: 18Hz conversion rate (typ)  CR = 2h: 9Hz conversion rate (typ)  CR = 3h: 4Hz conversion rate (typ)
FQ	Fault queue to trigger the ALERT pin  FQ = 0h: 1 fault (default)  FQ = 1h: 2 faults  FQ = 2h: 4 faults  FQ = 3h: 6 faults
POL	ALERT polarity control POL = 0: ALERT is active low (default) POL = 1: ALERT is active high
ТМ	ALERT thermostat mode control  TM = 0: ALERT is in comparator mode (default)  TM = 1: ALERT is in interrupt mode
SD	Shutdown control bit SD = 0: Device is in continuous conversion mode (default) SD = 1: Device is in shutdown mode

Figure 8-4. T<sub>I OW</sub>: Temperature Low Limit Register (pointer = 2h) [reset = 4B00h] (1)

	J LU	744 - 1		- 5 (1	, L		
15	14	13	12	11	10	9	8
L11	L10	L9	L8	L7	L6	L5	L4
			R/W	-4Bh			
7	6	5	4	3	2	1	0
L3	L2	L1	L0		Rese	erved	
R/W-0h					R-	0h	

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

(1)  $4B00h = 75^{\circ}C$ .

Table 8-4. T<sub>LOW</sub> Register Description

Name	Description			
L11 to L4	The 8 MSBs of the temperature low limit (resolution of 1°C)			
L3 to L0	The 4 LSBs of the temperature low limit (resolution of 0.0625°C)			

Figure 8-5. T<sub>HIGH</sub>: Temperature High Limit Register (pointer = 3h) [reset = 5000h] <sup>(1)</sup>

15	14	13	12	11 10 9			8					
H11	H10	H9	H8	H7	H6	H5	H4					
R/W-50h												
7	6	5	4	3	0							
Н3	H2	H1	H0	Reserved								
	R/W	V-0h			R-	0h						

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

(1)  $5000h = 80^{\circ}C$ .

Table 8-5. T<sub>HIGH</sub> Register Description

Name	Description					
H11 to H4	The 8 MSBs of the temperature high limit (resolution of 1°C)					
H3 to H0	The 4 LSBs of the temperature high limit (resolution of 0.0625°C)					

# 9 Application and Implementation

#### Note

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

## 9.1 Application Information

The TMP75B-Q1 is used to measure the PCB temperature where the device is mounted. The programmable address options allow up to eight locations on the board to be monitored on a single serial bus. Connecting the ALERT pins together and programming the temperature limit registers to desired values allows for a temperature watchdog operation of all devices, interrupting the host controller only if the temperature exceeds the limits.

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# 9.2 Typical Application

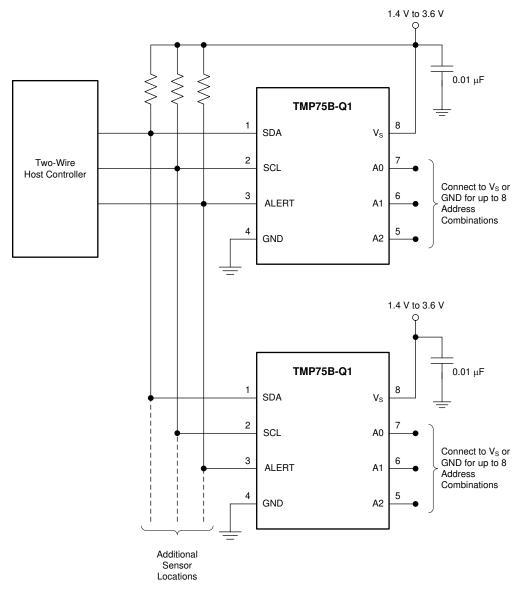


Figure 9-1. Temperature Monitoring of Multiple Locations on a PCB

### 9.2.1 Design Requirements

The TMP75B-Q1 only requires pullup resistors on SDA and ALERT, although a pullup resistor is typically present on the SCL as well. A  $0.01\mu F$  bypass capacitor on the supply is recommended, as shown in Figure 9-1. The SCL, SDA, and ALERT lines can be pulled up to a supply that is equal to or higher than  $V_S$  through the pullup resistors. To configure one of eight different addresses on the bus, connect A0, A1, and A2 to either  $V_S$  or GND.

#### 9.2.2 Detailed Design Procedure

The TMP75B-Q1 must be placed in close proximity to the heat source to be monitored, with a proper layout for good thermal coupling. This placement verifies that temperature changes are captured within the shortest possible time interval.

### 9.2.3 Application Curve

Figure 9-2 shows the step response of the TMP75B-Q1 to a submersion in an oil bath of 100°C from room temperature (27°C). The time-constant, or the time for the output to reach 63% of the input step, is 1.5 seconds.

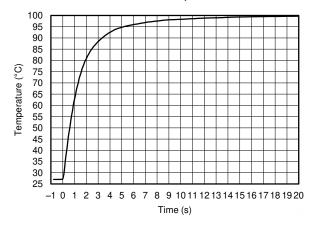


Figure 9-2. Temperature Step Response

### 9.3 Power-Supply Recommendations

The TMP75B-Q1 operates with power supply in the range of 1.4V to 3.6V. The device is optimized for operation at 1.8V supply but can measure temperature accurately in the full supply range.

A power-supply bypass capacitor is recommended; place this capacitor as close as possible to the supply and ground pins of the device. A typical value for this supply bypass capacitor is 0.01µF. Applications with noisy or high-impedance power supplies can require additional decoupling capacitors to reject power-supply noise.

### 9.4 Layout

## 9.4.1 Layout Guidelines

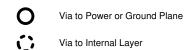
Place the temperature sensor as close as possible and run copper planes on the ground or other layers to provide good thermal coupling to the heat source for fast settling and accurate measurement of the temperature of the hot spot.

Place the power-supply bypass capacitor as close as possible to the supply and ground pins.

Pull up the open-drain output pins (SDA and ALERT) to a supply voltage rail ( $V_S$  or higher but up to 3.6V) through  $10k\Omega$  pullup resistors. Smaller values of the resistors can be used to compensate for long bus traces that can cause an increase in capacitance and slow rise time for the open-drain outputs; the values must not be less than  $1k\Omega$  to avoid self-heating effects due to increased current through the part in the low states of the outputs.



## 9.4.2 Layout Example



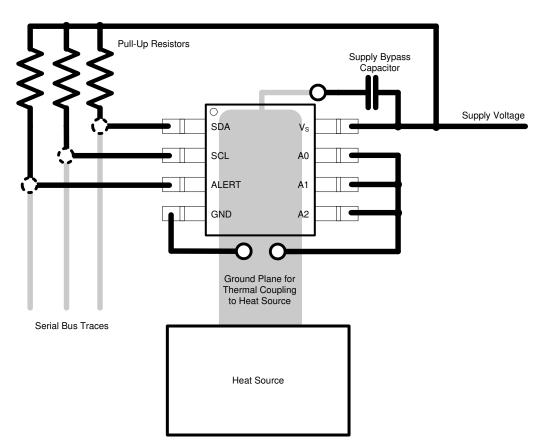


Figure 9-3. Layout Example

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## 10 Device and Documentation Support

## **10.1 Documentation Support**

#### 10.1.1 Related Documentation

Texas Instruments, TMP75xEVM User's Guide, EVM user's guide

## 10.2 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. Click on *Notifications* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

## 10.3 Support Resources

TI E2E<sup>™</sup> support forums are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

Linked content is provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

#### 10.4 Trademarks

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## 10.5 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

#### 10.6 Glossary

TI Glossary

This glossary lists and explains terms, acronyms, and definitions.

## 11 Revision History

### Changes from Revision A (June 2022) to Revision B (October 2024)

Page

- Updated the number format for tables, figures, and cross-references throughout the document......
- Added the TMP75BTQDGKR device information in the specifications section and throughout the document..5

## Changes from Revision \* (October 2014) to Revision A (June 2022)

Page

- Updated the numbering format for tables, figures, and cross-references throughout the document.......
- Changed all instances of legacy terminology to controller and target where I<sup>2</sup>C is mentioned.......

## 12 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

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#### PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
							(6)				
TMP75BQDGKRQ1	ACTIVE	VSSOP	DGK	8	2500	RoHS & Green	NIPDAU   NIPDAUAG	Level-2-260C-1 YEAR	-40 to 125	T75BQ	Samples
TMP75BQDGKTQ1	OBSOLETE	VSSOP	DGK	8		TBD	Call TI	Call TI	-40 to 125	T75BQ	
TMP75BQDQ1	OBSOLETE	SOIC	D	8		TBD	Call TI	Call TI	-40 to 125	T75BQ	
TMP75BQDRQ1	ACTIVE	SOIC	D	8	2500	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	T75BQ	Samples
TMP75BTQDGKRQ1	ACTIVE	VSSOP	DGK	8	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	75BTQ	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead finish/Ball material Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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# **PACKAGE OPTION ADDENDUM**

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In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

#### OTHER QUALIFIED VERSIONS OF TMP75B-Q1:

NOTE: Qualified Version Definitions:

• Catalog - TI's standard catalog product

# **PACKAGE MATERIALS INFORMATION**

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## TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



#### \*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TMP75BQDGKRQ1	VSSOP	DGK	8	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
TMP75BQDRQ1	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TMP75BTQDGKRQ1	VSSOP	DGK	8	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1



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## \*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TMP75BQDGKRQ1	VSSOP	DGK	8	2500	353.0	353.0	32.0
TMP75BQDRQ1	SOIC	D	8	2500	356.0	356.0	35.0
TMP75BTQDGKRQ1	VSSOP	DGK	8	2500	353.0	353.0	32.0



SMALL OUTLINE INTEGRATED CIRCUIT



## NOTES:

- 1. Linear dimensions are in inches [millimeters]. Dimensions in parenthesis are for reference only. Controlling dimensions are in inches. Dimensioning and tolerancing per ASME Y14.5M.
- 2. This drawing is subject to change without notice.
- 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 [0.15] per side.
- 4. This dimension does not include interlead flash.
- 5. Reference JEDEC registration MS-012, variation AA.



SMALL OUTLINE INTEGRATED CIRCUIT



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE INTEGRATED CIRCUIT



#### NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.





SMALL OUTLINE PACKAGE



#### NOTES:

PowerPAD is a trademark of Texas Instruments.

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

  2. This drawing is subject to change without notice.

  3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-187.



SMALL OUTLINE PACKAGE



NOTES: (continued)

- 6. Publication IPC-7351 may have alternate designs.
- 7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.
- 8. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.
- 9. Size of metal pad may vary due to creepage requirement.



SMALL OUTLINE PACKAGE



NOTES: (continued)

- 11. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 12. Board assembly site may have different recommendations for stencil design.



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